

**500V N-Channel Enhancement Mode Power MOSFET**

**MAIN CHARACTERISTICS**

<b>I<sub>D</sub></b>	10A
<b>V<sub>DSS</sub></b>	500V
<b>R<sub>DS(on)-typ(@V<sub>GS</sub>=10V)</sub></b>	<0.56Ω( <b>Typ:0.45Ω</b> )

**FEATURES**

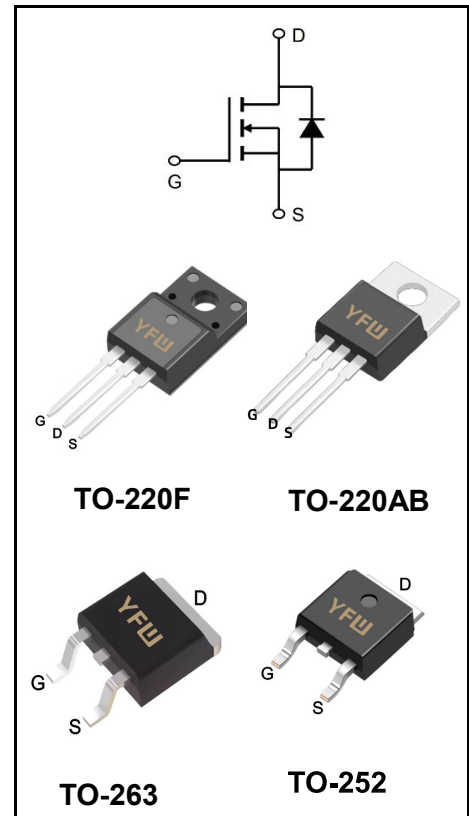
- ◆Fast Switching
- ◆Low ON Resistance
- ◆Low Gate Charge
- ◆100% Single Pulse avalanche energy Test

**APPLICATIONS**

- ◆Power switch circuit of adaptor and charger.

**MECHANICAL DATA**

- ◆Case: Molded plastic
- ◆Mounting Position: Any
- ◆Molded Plastic: UL Flammability Classification Rating 94V-0
- ◆Lead free in compliance with EU RoHS 2011/65/EU directive
- ◆Solder bath temperature 275°C maximum,10s per JESD 22-B106



**Maximum Ratings at T<sub>c</sub>=25°C unless otherwise specified**

Characteristics	Symbols	Value			Units
		220AB/263	220F	252	
Drain-Source Voltage	<b>V<sub>DS</sub></b>	500			<b>V</b>
Gate - Source Voltage	<b>V<sub>GS</sub></b>	±30			<b>V</b>
Continuous drain current	<b>I<sub>D</sub></b>	10			<b>A</b>
Pulsed Drain Current (Note1)	<b>I<sub>DM</sub></b>	40			<b>A</b>
Power dissipation	<b>P<sub>D</sub></b>	130	40	130	<b>W</b>
Single Pulse Avalanche Energy(Note1)	<b>E<sub>AS</sub></b>	580			<b>mJ</b>
Operating Temperature Range	<b>T<sub>J</sub></b>	150			<b>°C</b>
Storage Temperature Range	<b>T<sub>STG</sub></b>	-55 to +150			<b>°C</b>
Thermal Resistance, Junction-case	<b>R<sub>θJC</sub></b>	0.96	3.13	0.96	<b>°C/W</b>
Thermal Resistance, Junction to Ambient	<b>R<sub>θJA</sub></b>	62.5	62.5	62.5	<b>°C/W</b>

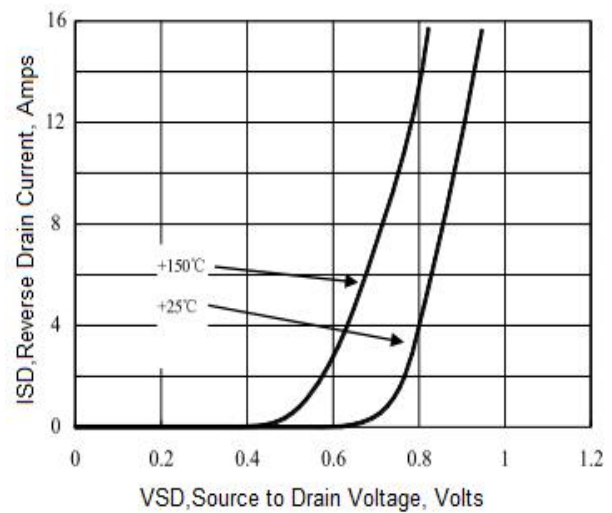
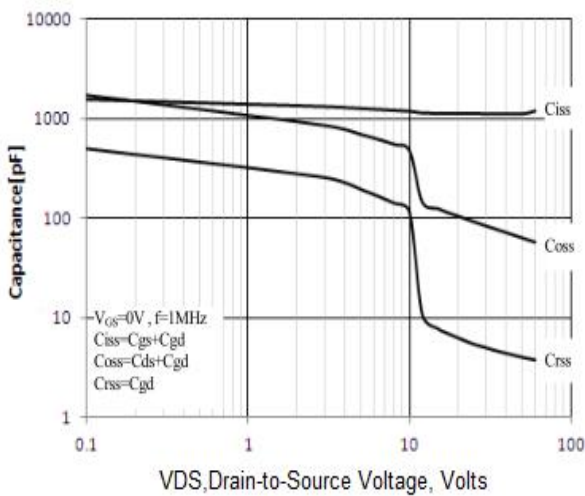
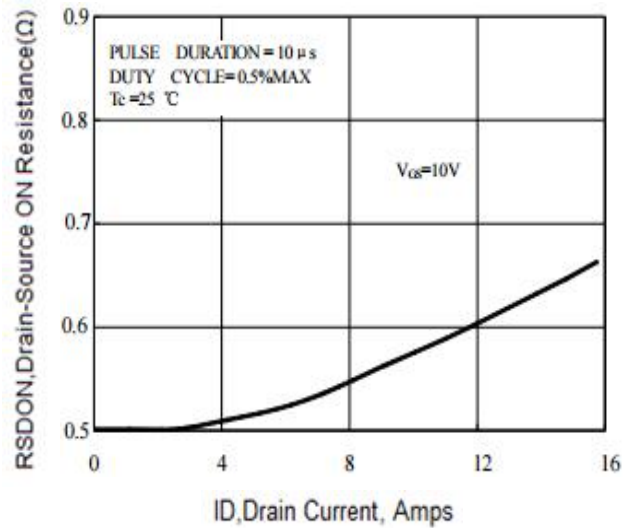
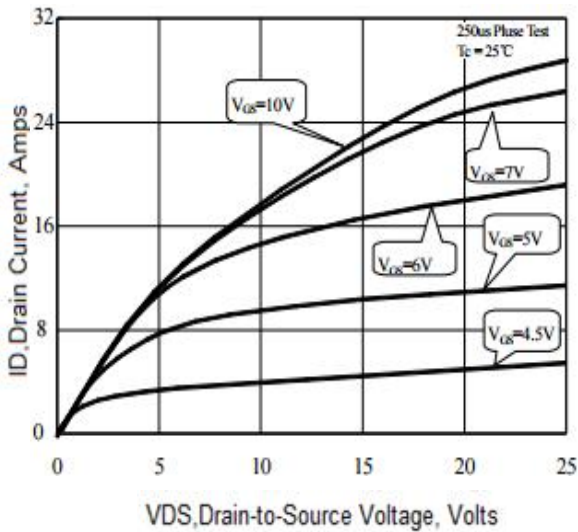
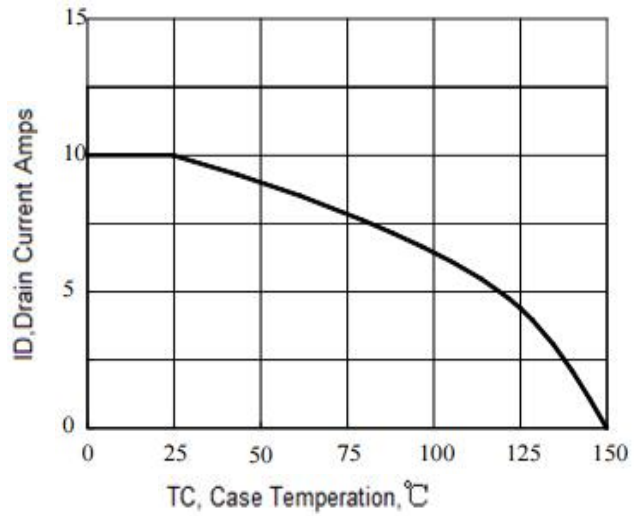
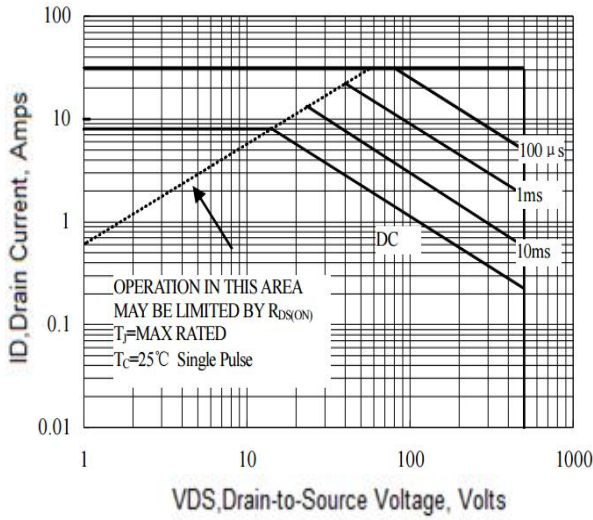
Note1:Pulse test: 300 μs pulse width, 2 % duty cycle

**Maximum Ratings at Tc=25°C unless otherwise specified**

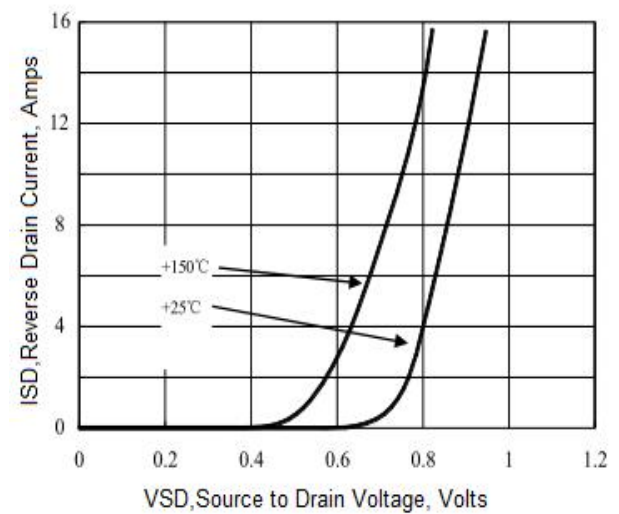
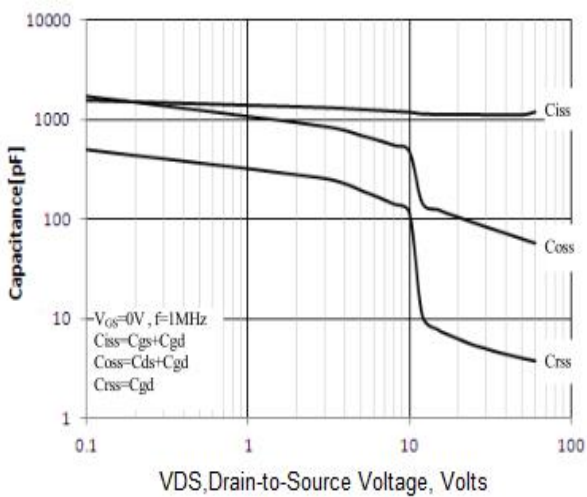
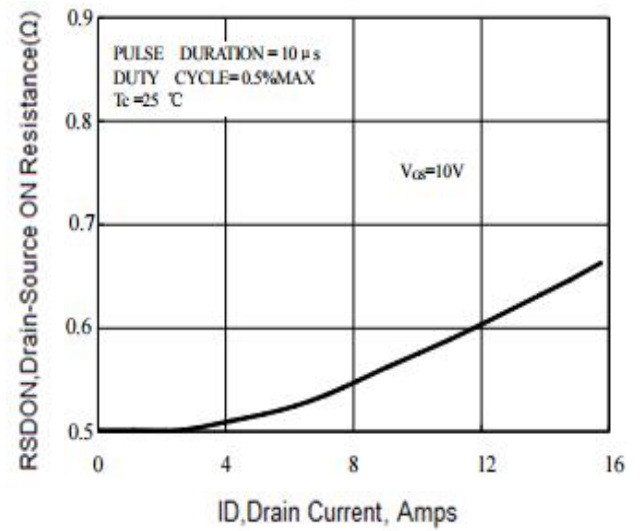
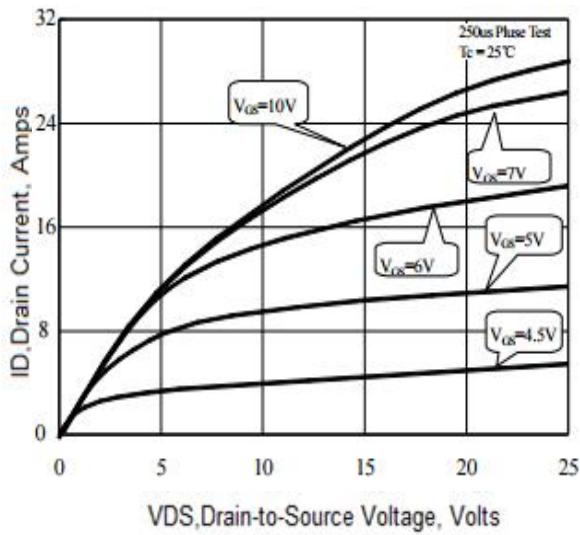
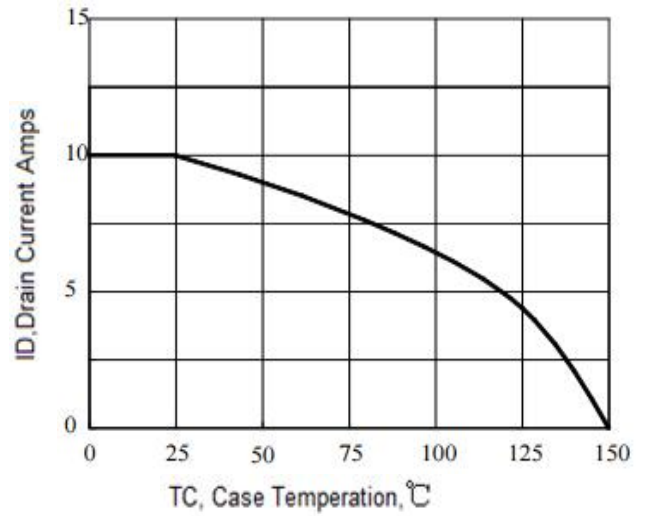
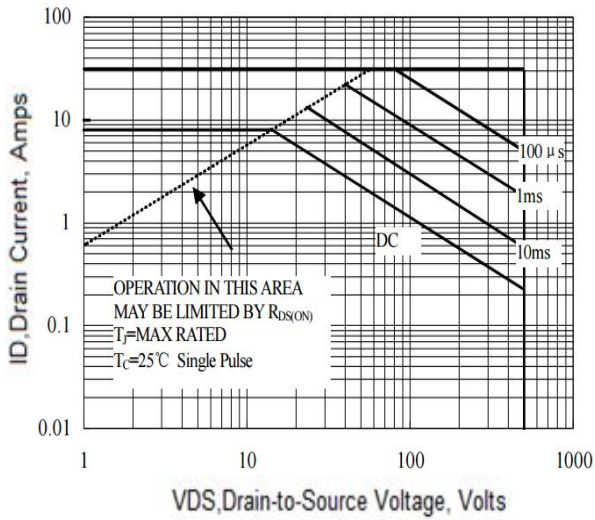
Characteristics	Test Condition	Symbols	Min	Typ	Max	Units
Drain-Source Breakdown Voltage	$V_{GS}=0V, I_D=250\mu A$	<b><math>BV_{DSS}</math></b>	500	-	-	<b>V</b>
Drain-Source Leakage Current	$V_{DS}=500V, V_{GS}=0V$	<b><math>I_{DSS}</math></b>	-	-	1	<b><math>\mu A</math></b>
Gate-Source Leakage Current	$V_{DS} = \pm 30V, V_{GS} = 0 V$	<b><math>I_{GSS}</math></b>	-	-	$\pm 100$	<b>nA</b>
Gate -Threshold Voltage	$V_{DS}=V_{GS}, I_D=250\mu A$	<b><math>V_{GS(th)}</math></b>	2.0	-	4	<b>V</b>
Drain-Source On-State Resistance	$V_{GS} = 10 V, I_D = 5 A$	<b><math>R_{DS(ON)}</math></b>	-	0.45	0.56	<b><math>\Omega</math></b>
Forward Transconductance	$V_{GS}=15V, I_D=5A$	<b><math>g_{fs}</math></b>	-	10	--	<b>S</b>
Input Capacitance	$V_{GS}=0V$ $V_{DS}=25V$ $f=1MHz$	<b><math>C_{iss}</math></b>	-	1620	-	<b>pF</b>
Output Capacitance		<b><math>C_{oss}</math></b>	-	156	-	
Reverse Transfer Capacitance		<b><math>C_{rss}</math></b>	-	7	-	
Turn-on delay time	$I_D = 10 A$ $V_{DD} = 250 V$ $R_G = 10 \Omega$	<b><math>t_{d(on)}</math></b>	-	25	-	<b>ns</b>
Rise Time		<b><math>T_r</math></b>	-	20	-	
Turn-Off Delay Time		<b><math>t_{d(OFF)}</math></b>	-	50	-	
Fall Time		<b><math>t_f</math></b>	-	20	-	
Total Gate Charge	$I_D = 10 A$ $V_{DD} = 400 V$ $V_{GS} = 10 V$	<b><math>Q_g</math></b>	-	32	-	<b>nC</b>
Gate-Source Charge		<b><math>Q_{gs}</math></b>	-	8	-	
Gate-Drain Charge		<b><math>Q_{gd}</math></b>	-	12	-	
Diode forward current		<b><math>I_S</math></b>	-	-	10	<b>A</b>
Maximun Body-Diode Pulsed Current(Note2)		<b><math>I_{SM}</math></b>	-	-	40	<b>A</b>
Diode Forward Voltage	$I_S=10A$	<b><math>V_{SD}</math></b>	-	-	1.4	<b>V</b>
Reverse Recovery Time(Note2)		<b><math>trr</math></b>	-	398	-	<b>ns</b>
Reverse Recovery Charge(Note2)	$I_{SD} = 10A, V_{GS} = 0 V,$ $di_F / dt = 100 A/\mu s$	<b><math>Q_{rr}</math></b>	-	2.5	-	<b><math>\mu C</math></b>

**Note2:Pulse test: 300  $\mu s$  pulse width, 2 % duty cycle**

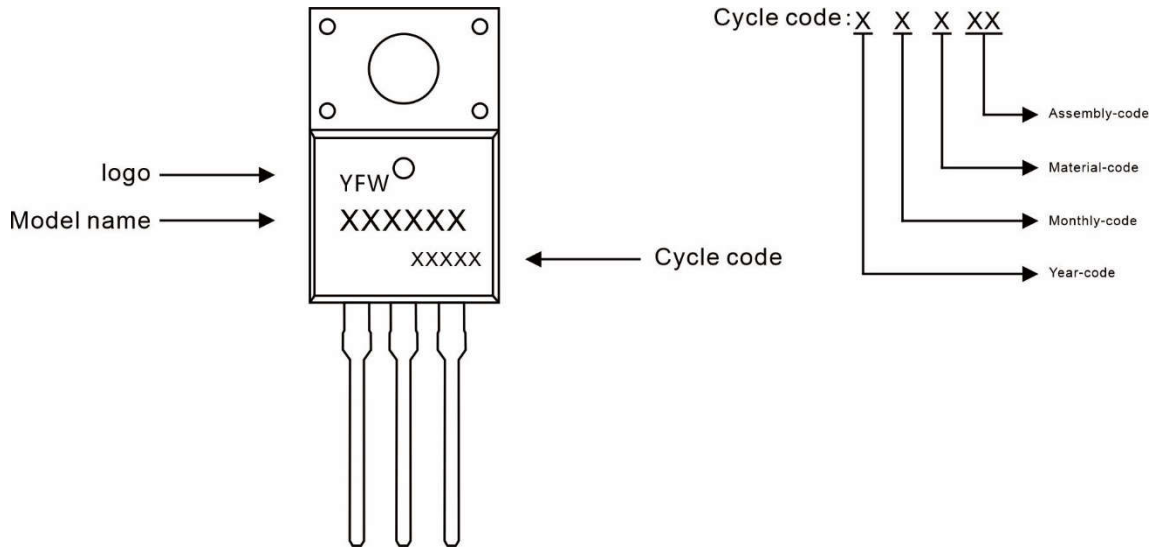
**Ratings and Characteristic Curves**



**Ratings and Characteristic Curves**



**Marking Diagram**



**Ordering information**

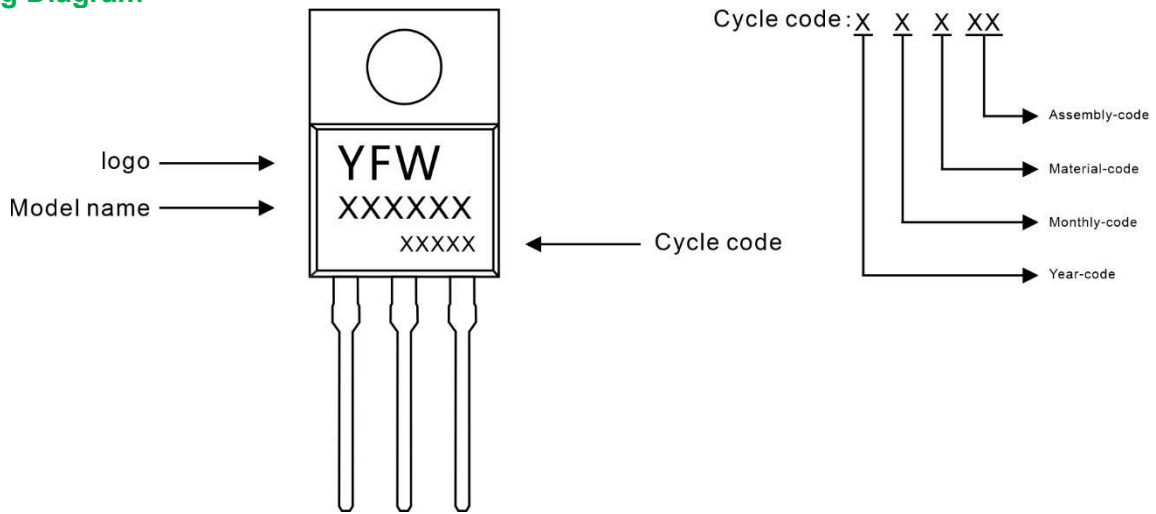
Model name	Package	Unit Weight	Base Quantity	Packing Quantity
YFW10N50AF	TO-220F	0.06oz(1.74g)	50pcs/tube	1000PCS/Box 5000PCS/Carton

**Package Dimensions**

**TO-220F**

Symbol	Millimeter		Inches	
	Min.	Max.	Min.	Max.
A	4.50	4.90	0.177	0.193
A1	2.34	2.74	0.092	0.108
A2	2.66	2.86	0.105	0.113
b	0.75	0.85	0.030	0.033
b1	1.24	1.44	0.049	0.057
c	0.40	0.60	0.016	0.024
D	10.00	10.32	0.394	0.406
E	15.75	16.05	0.620	0.632
e	2.44	2.64	0.096	0.104
e1	4.88	5.28	0.192	0.208
F	3.10	3.5	0.122	0.138
L	13.50	13.90	0.531	0.547
L1	2.90	3.30	0.114	0.130
Φ	3.10	3.30	0.122	0.130

**Marking Diagram**



**Ordering information**

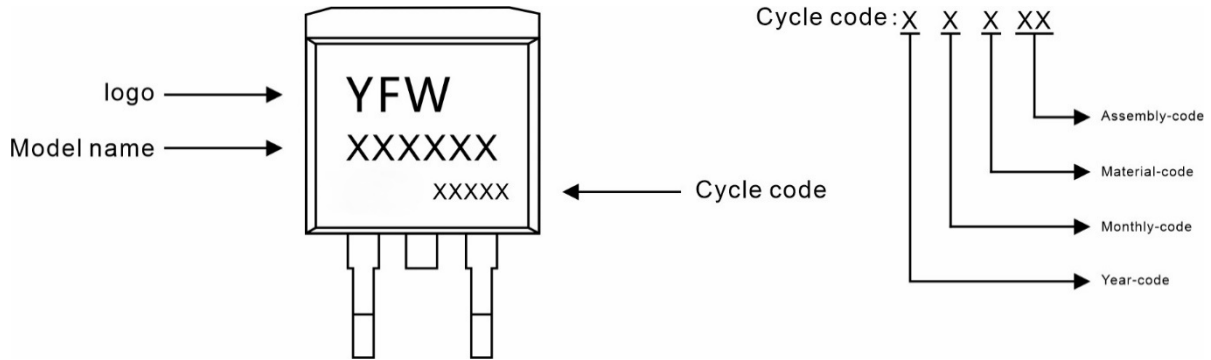
Model name	Package	Unit Weight	Base Quantity	Packing Quantity
YFW10N50AT	TO-220AB	0.07oz(1.96g)	50pcs/tube	1000PCS/Box 5000PCS/Carton

**Package Dimensions**

**TO-220AB**

Symbol	Millimeter		Inches	
	Min.	Max.	Min.	Max.
A	4.30	4.70	0.169	0.185
A1	2.52	2.82	0.099	0.111
b	0.71	0.91	0.028	0.036
b1	1.17	1.37	0.046	0.054
c	0.30	0.50	0.012	0.020
c1	1.17	1.37	0.046	0.054
D	9.90	10.20	0.390	0.402
E	8.50	8.90	0.335	0.350
E1	12.00	12.50	0.472	0.492
e	2.44	2.64	0.096	0.104
e1	4.88	5.28	0.192	0.208
F	2.60	2.80	0.102	0.110
L	13.20	13.80	0.520	0.543
L1	3.80	4.20	0.150	0.165
Φ	3.60	3.96	0.142	0.156

**Marking Diagram**



**Ordering information**

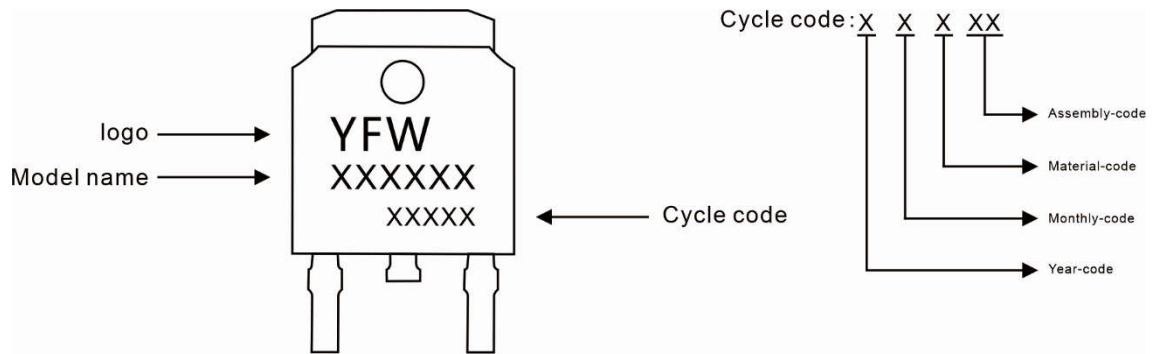
Model name	Package	Unit Weight	Base Quantity	Packing Quantity
YFW10N50AS	TO-263	0.04oz(1.16g)	800pcs/reel	1600pcs/box 8000pcs/Carton

**Package Dimensions**

TO-263

Dim	Millimeter		Inches	
	Min.	Max.	Min.	Max.
A	4.30	4.70	0.169	0.185
A1	0.00	0.15	0.000	0.006
A2	4.30	4.55	0.169	0.179
B	1.10	1.50	0.043	0.059
b	0.70	0.90	0.028	0.035
b1	1.20	1.50	0.047	0.059
c	0.30	0.60	0.012	0.024
c1	1.17	1.37	0.046	0.054
D	9.90	10.20	0.390	0.402
E	8.50	8.90	0.335	0.350
e	2.44	2.64	0.096	0.104
e1	4.88	5.28	0.192	0.208
L	15.00	15.30	0.591	0.602
L1	5.20	5.40	0.205	0.213
L2	2.40	2.60	0.094	0.102
L3	1.60	1.80	0.063	0.071

**Marking Diagram**



**Ordering information**

Model name	Package	Unit Weight	Base Quantity	Packing Quantity
YFW10N50AD	TO-252	0.011oz(0.32g)	2500pcs/reel	5000pcs/box 25000pcs/Cartron

**Package Dimensions**

TO-252

Dim	Millimeter		Inches	
	Min.	Max.	Min.	Max.
A	2.20	2.50	0.087	0.098
A1	0.00	0.12	0.000	0.005
A2	2.20	2.40	0.087	0.094
B	1.20	1.60	0.047	0.063
b	0.50	0.70	0.020	0.028
b1	0.70	0.90	0.028	0.035
c	0.40	0.60	0.016	0.024
c1	0.40	0.60	0.016	0.024
D	6.35	6.65	0.250	0.262
D1	5.20	5.40	0.205	0.213
E	5.40	5.70	0.213	0.224
e	2.20	2.40	0.087	0.094
e1	4.40	4.80	0.173	0.189
L	10.00	11.00	0.393	0.433
L1	2.70	3.10	0.106	0.122
L2	1.40	1.80	0.055	0.071
L3	0.90	1.50	0.035	0.059



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